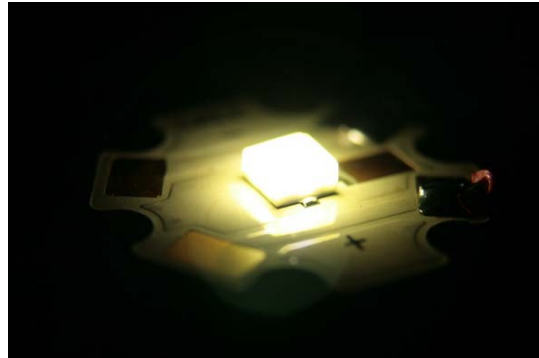


Quantum Dot Downconverters: LED Package Integration

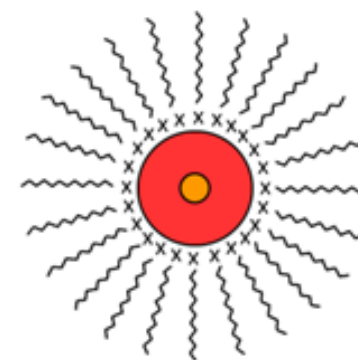
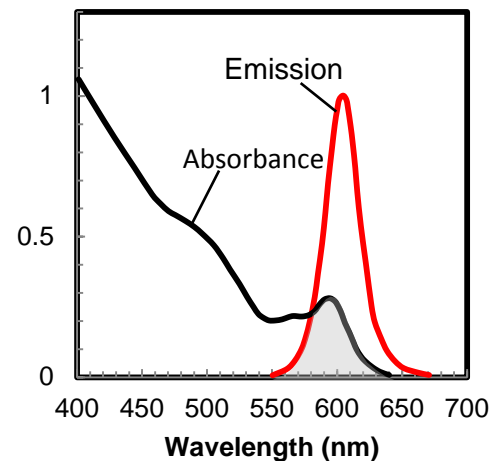
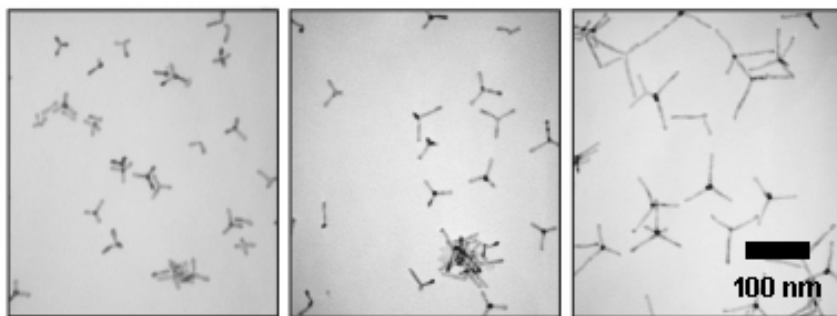
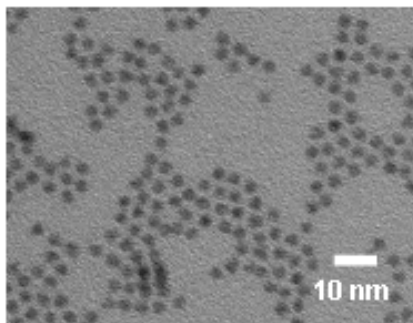
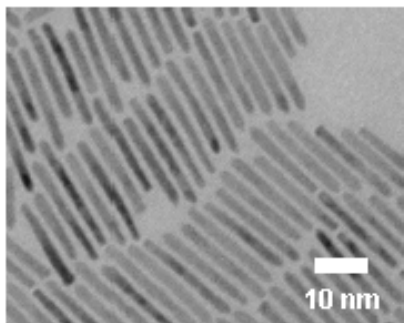


*Julian Osinski, Ph.D.
VP of Product Marketing
Pacific Light Technologies*

DOE SSL R&D Workshop, Tampa, FL, January 29, 2014

QD Nanoparticle Emitters

CdS, CdSe, CdTe

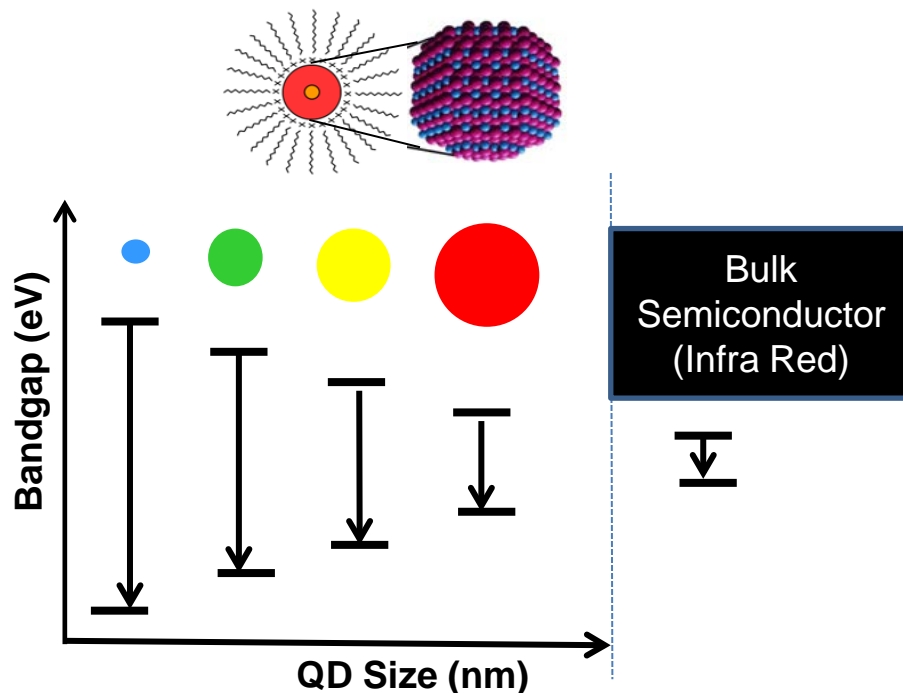


Murray, C. B.; Norris, D. J.; Bawendi, M. G. *JACS*, **1993**, 115, 8706
Alivisatos, A. P. *Nature Materials* **2003**, 2, 382

**Optical properties controlled
by size, materials, shape**

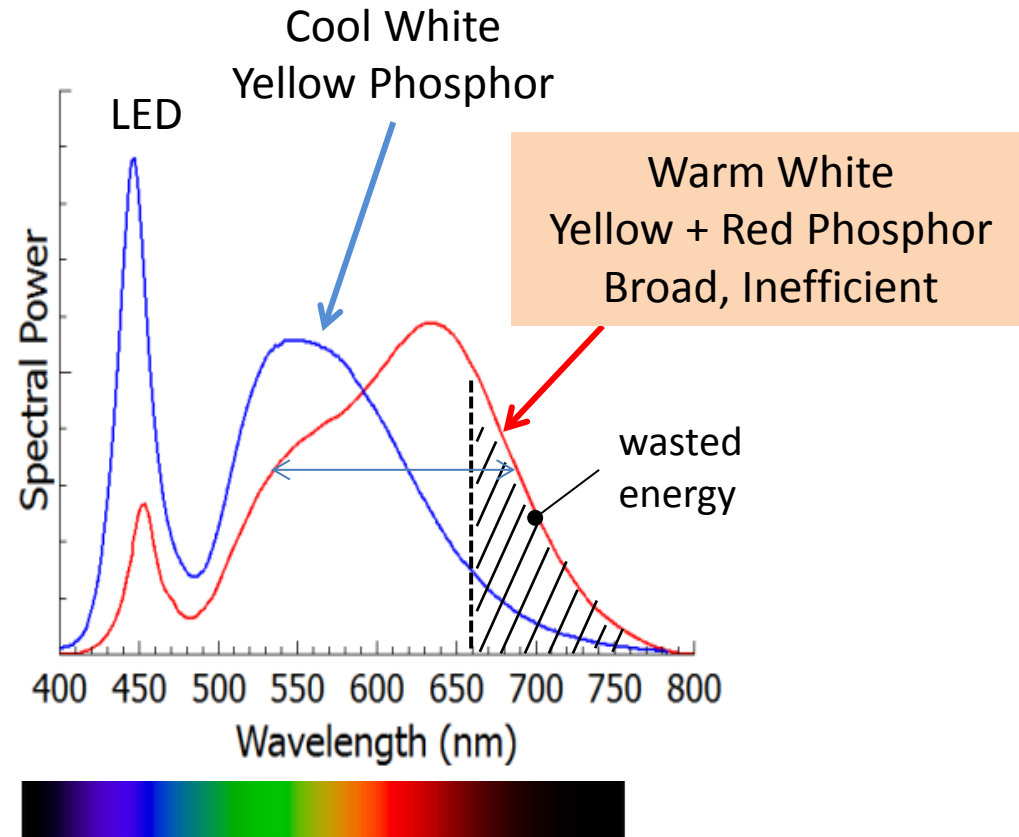
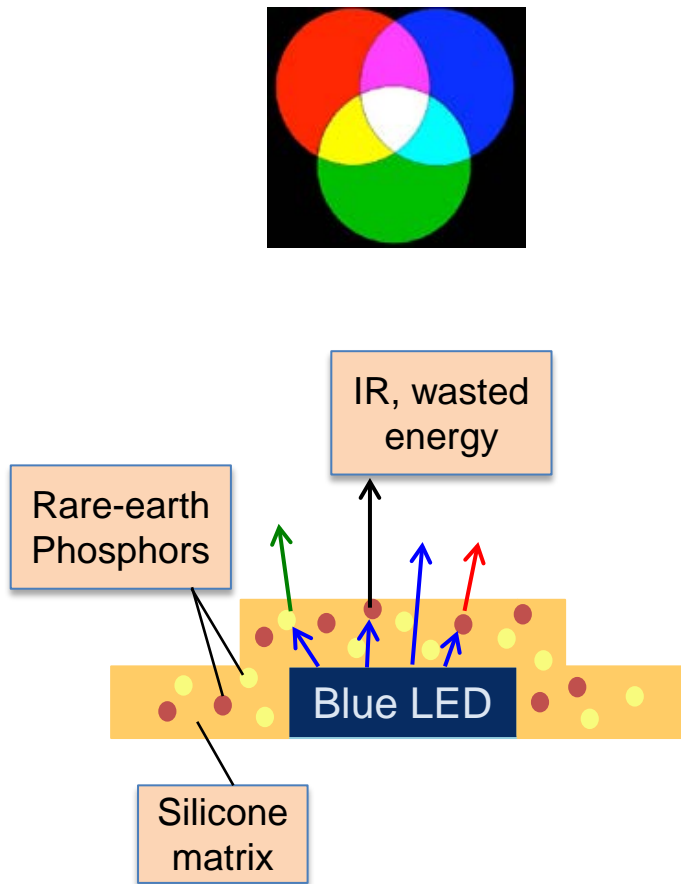


Advantages of QD downconverters



- *Precise peak emission placement (± 2 nm)*
- *Very narrow emission peaks (< 35 nm)*
- *Fast radiative decay times—(ns compared to μ s)*
- *Very high efficiencies*
- *Soluble--Composites can be clear*

White Light LEDs: How It's Done Today

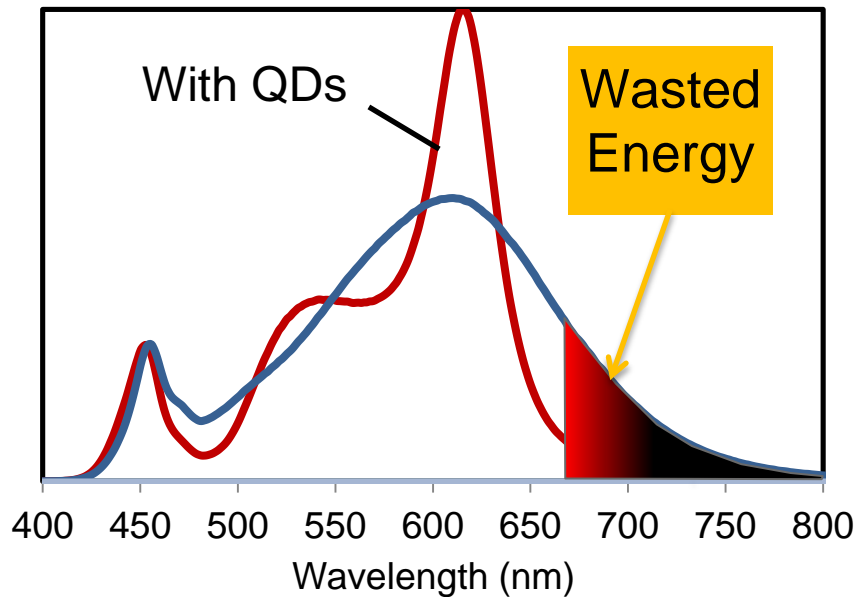


Blue LEDs + Phosphors Produce White Light



Why QDs in LEDs?

QDs Simultaneously Increase Efficacy and Improve Color Quality



- Red or other wavelengths where you want them
- Efficacy improvements thanks to narrow spectrum: **20-40% benefit for WW**
- Customizable spectrum allows improved CRI: **>90 easily obtained**

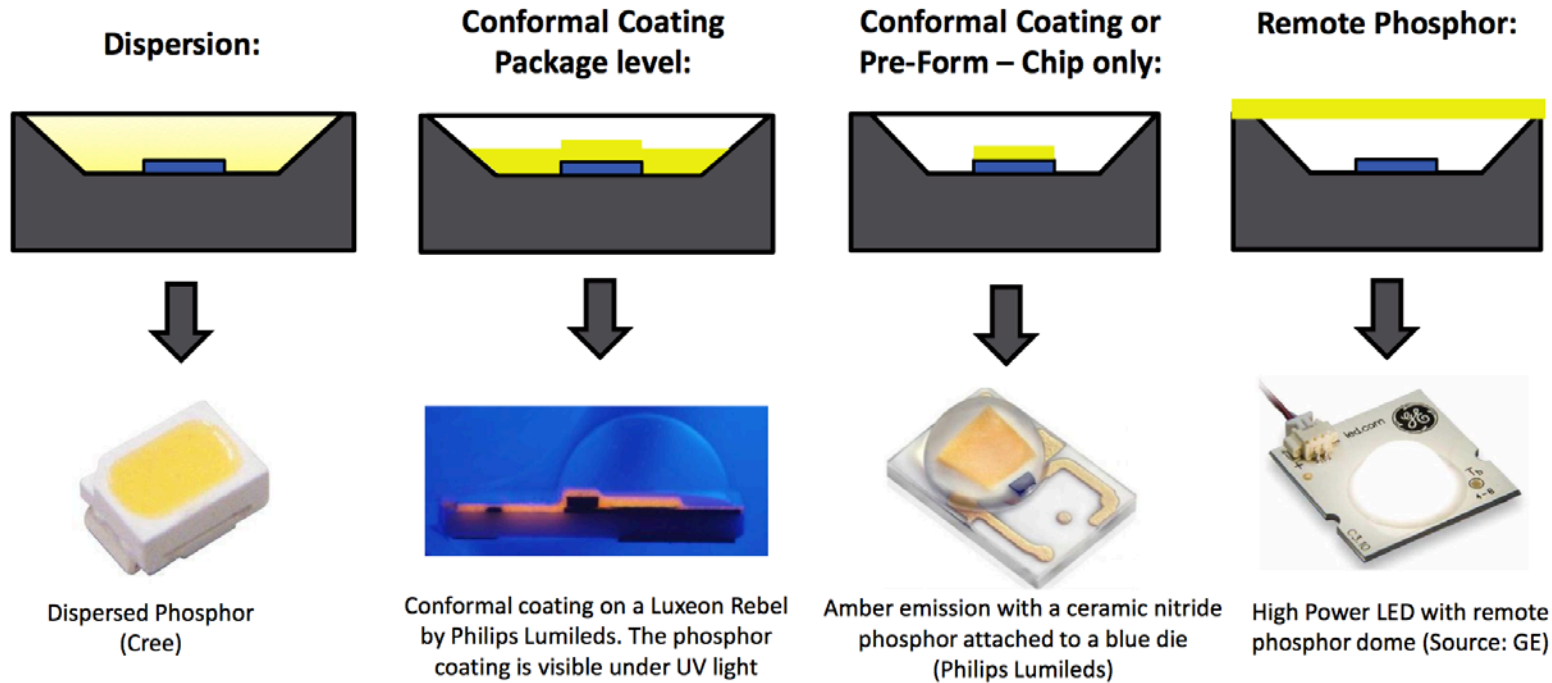


QDs Reduce System Cost

- Fewer LEDs required in a luminaire
- Smaller drivers and heatsinks required



Replacing Phosphors with QDs in LED Packages



Source: Yole

Quantum dots must perform on-chip to contribute significantly to solid-state lighting

On-chip QDs: Practical Requirements

Quantum dot materials need to stand up to a host of environmental demands:

- Mixing into silicone: room air, ambient conditions, possibly with phosphors or fillers
- Curing (150C, 1-2hrs)
- Lens Molding
- Solder Reflow (260C, ~10 sec)
- Non-hermetic use condition at high temperature and blue flux

Choice of Silicones

- Two major types in common usage
- Each LED manufacturer has their favorites
- Ideally, QD performance is independent of the matrix
- Other considerations: viscosity, hardness, darkening...

| | Methyl | Phenyl |
|--|-----------|-----------|
| Refractive Index (n_p) | 1.41 | 1.53-1.54 |
| Transmittance | Excellent | Excellent |
| Light Stability | Excellent | Very Good |
| Gas Barrier | Fair | Very Good |

Phenyl encapsulants may enhance efficiency of light extraction of LEDs.

Source: Dow Corning



Typical Two-part Silicone System

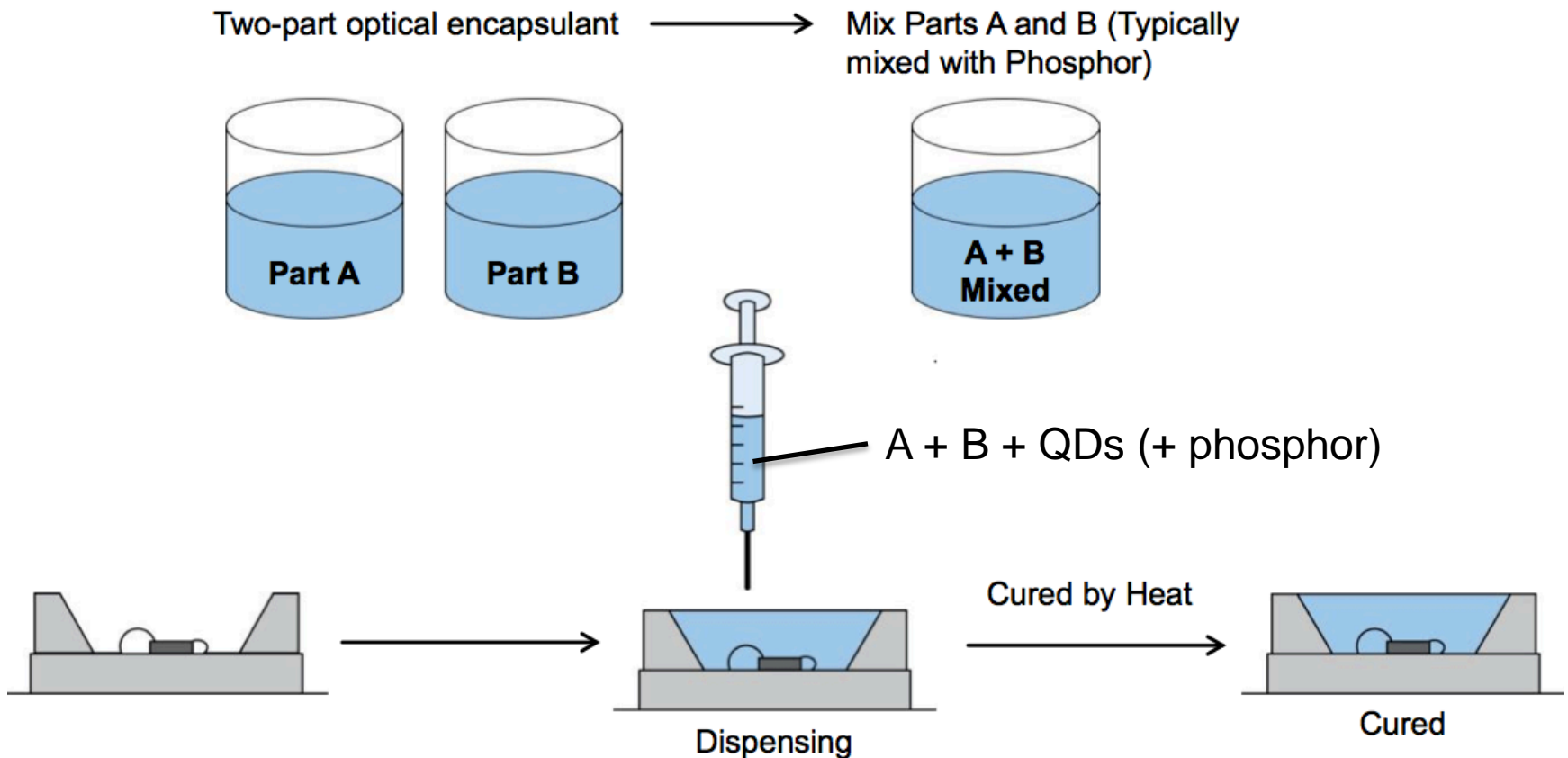


Image Source: Dow Corning

QD Concentration Control

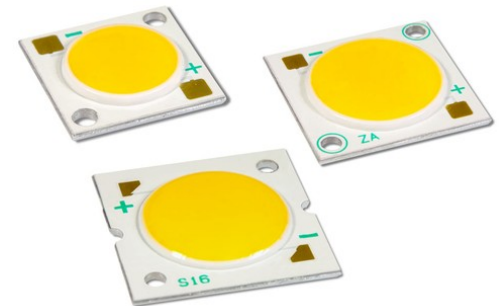
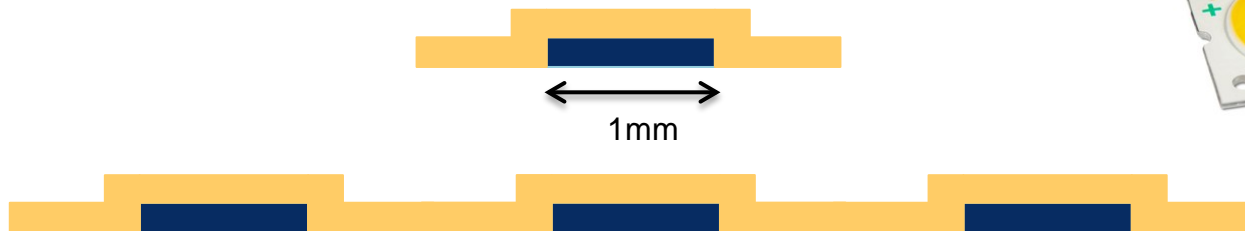


- Concentrations must be adjusted to accommodate various thickness requirements of the silicone film above the chip.
- Typical film thickness range 50-400 microns
- The **number-density** of QDs above the chip determines the conversion ratio
- The **mass** per unit area or volume of the QDs required is very different than that of phosphors and in total is ***100's of times less!***

Quantum dots can be applied on-chip using most any application techniques and package types

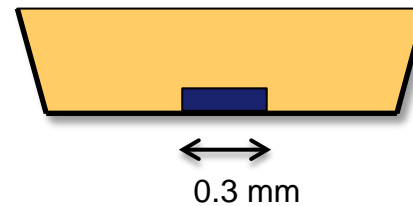
Spraying, printing, dispensing, etc:

1. Conformal or near-conformal coatings: most high power SSL packages use this approach
 - Includes COB packages and arrays
 - Customizable concentrations for various thicknesses
 - Highest fluxes and temps
 - 100+ W/cm², >125C

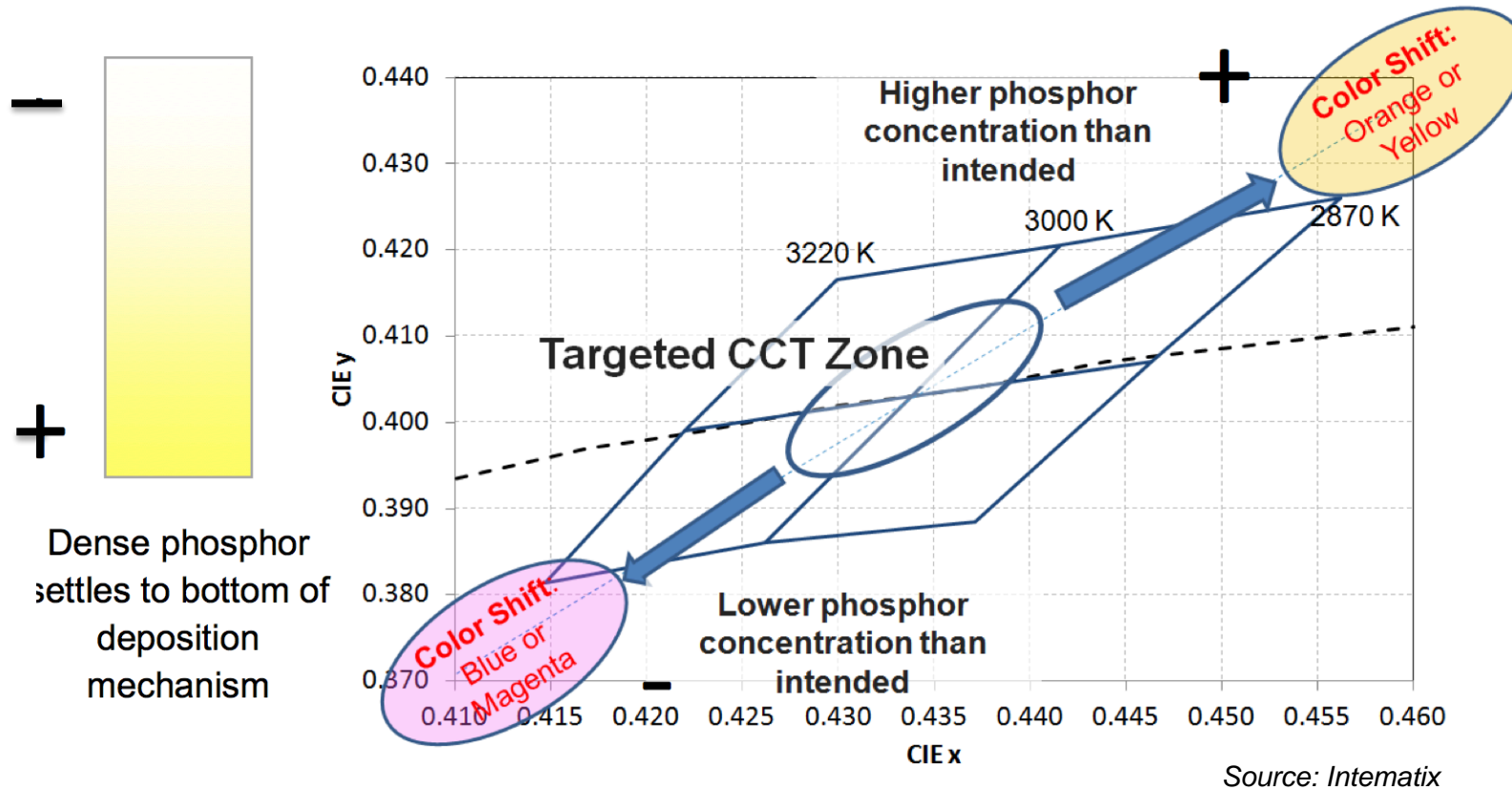


Package Types II

2. Volume casting: “Goop in a cup”
- High volume, mid-power package design
 - QDs don't settle!
 - 20-60 W/cm², ~110C
 - This pkg type also used for display backlights



Settling Issues with Phosphors

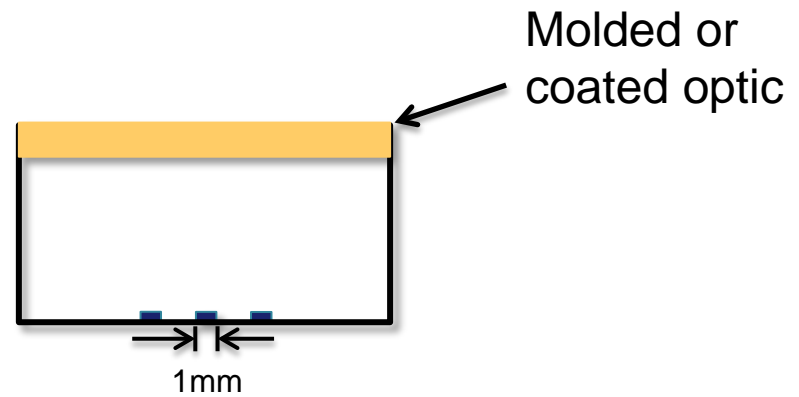


This problem goes away with QDs

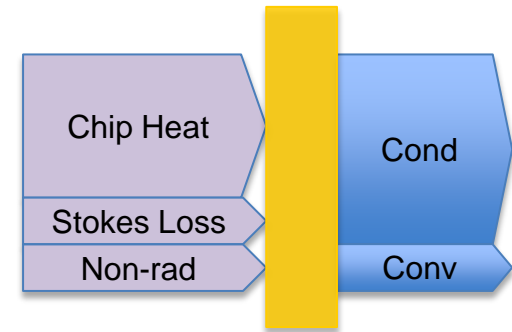
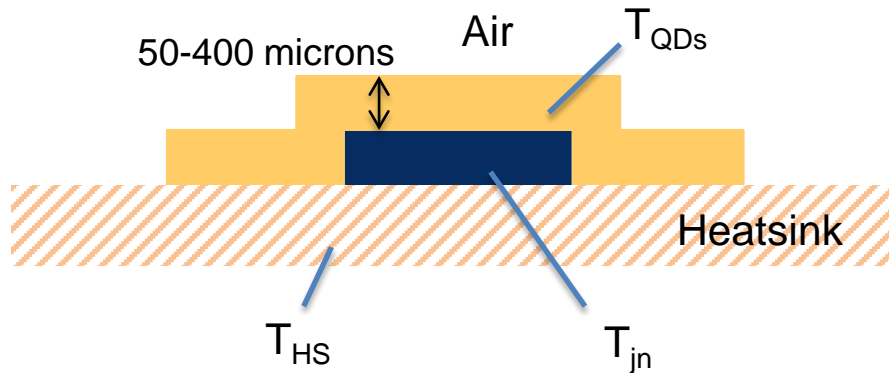
Package Types III

3. Remote Optic

- Lowest temperature and flux conditions
 - $<10\text{W}/\text{cm}^2$, $<100^\circ\text{C}$ typically
- 10% or more higher efficiency claimed due to photon recycling
- Most cost-sensitive, uncertain market acceptance



Contributions to Heating

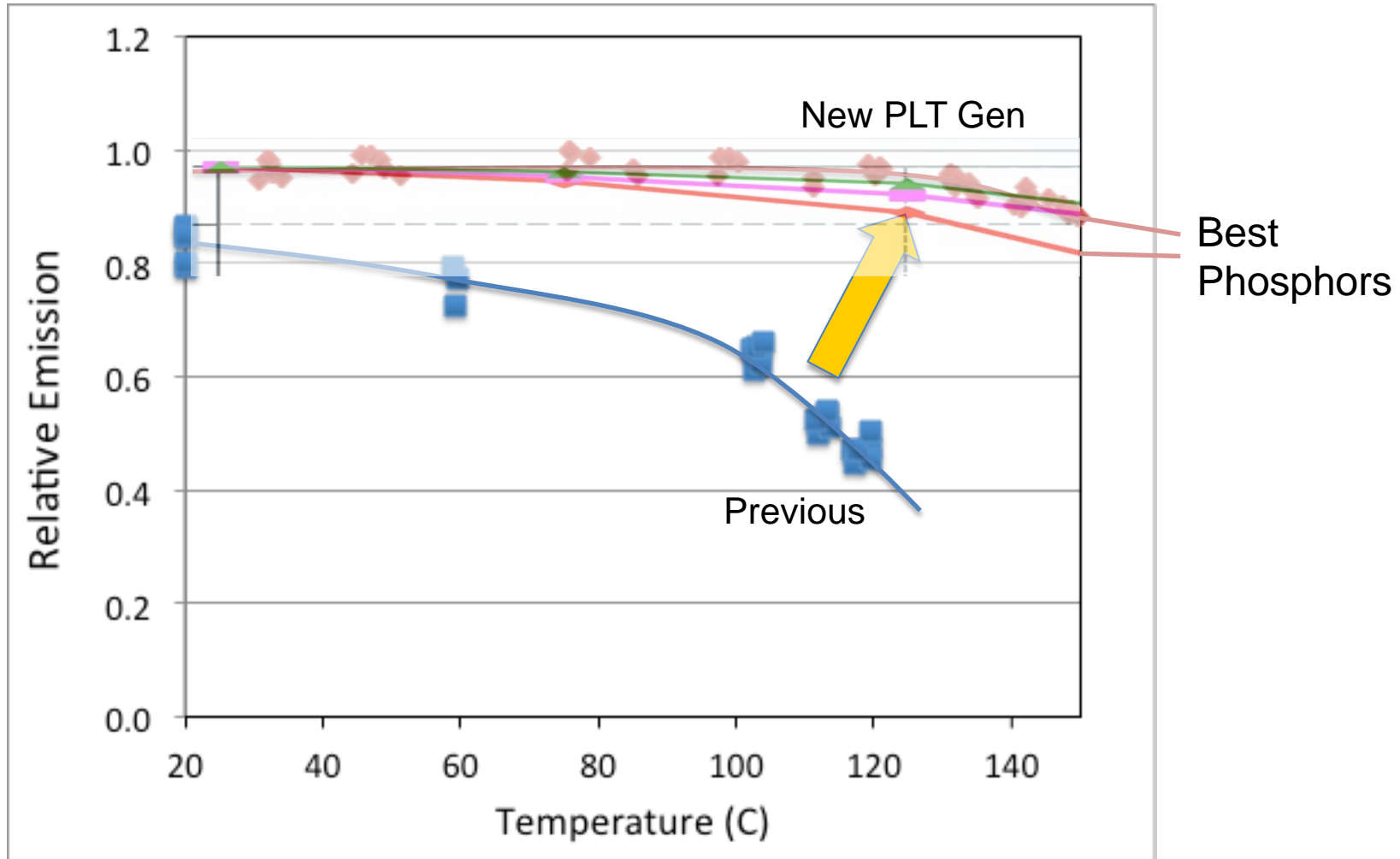


QD temperature is a function of:

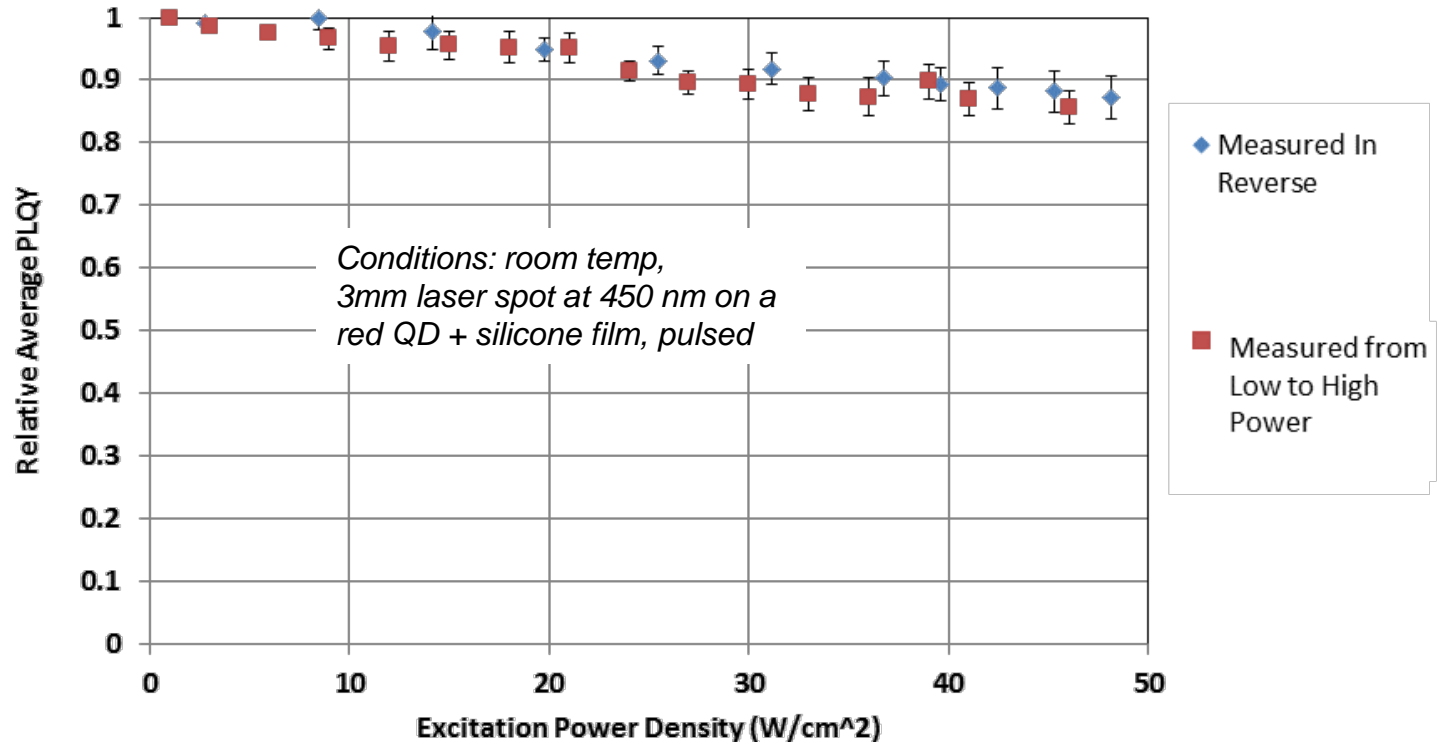
- Conductive heating from chip
- Stokes loss
- Non-radiative losses, quantum efficiency $< 100\%$
- Conductive/convective cooling from surfaces

Net temperature rise for mid-power LEDs typically 10-20C over T_{jn}
Measurable by thermal camera or monitoring wavelength shift of QD emission.

Temperature Dependence: Low thermal quenching



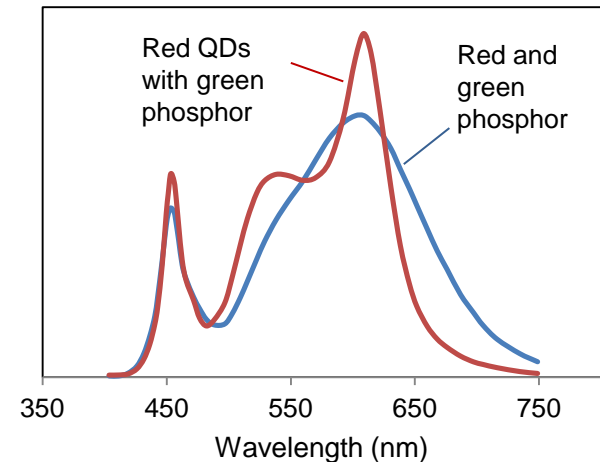
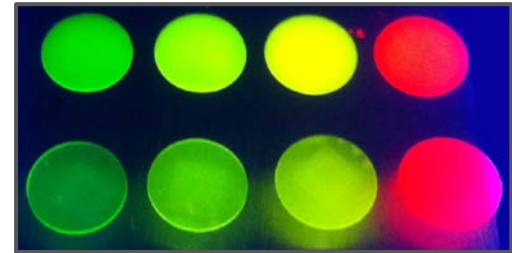
PLT Results on Intensity Dependence



- For PLT materials, no cliff observed up to 50 W/cm, measured in silicone at ambient conditions
- Other tests have been made out to 1000 W/cm²

On-chip QD requirements: Summary

- Compatibility with silicones and mfg processes
- Tolerant to high temperatures
- Tolerant to high pump intensity
- Maintenance of high quantum efficiencies over life
- Ideally without a hermeticity requirement



Actual operational data

Thank you!

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